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Enhancement of Blue Doping-Free and Hyperfluorescent Organic Light Emitting Diode Performance through Triplet—Triplet Annihilation in the Derivatives of Anthracene and Carbazole

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yethoxy groups are linked with anthracene-based moieties in a series of designed and synthesized compounds with the aim to obtain triplet levels lower than 2 eV and efficient triplet harvesting in electroluminescent devices. The upconversion of triplet excitons is studied theoretically and experimentally. The triplet fusion is responsible for the appearance of blue delayed emission with lifetimes up to 0.15 ms, which is detected for the methoxycontaining compound by photophysical investigation. The *tert*butylated emitter shows good performance in organic light emitting diodes (OLEDs), reaching an external quantum efficiency of 5.9% with the 1931 Commission Internationale de l'Éclairage



coordinates of (0.14, 0.12). The time-of-flight measurements demonstrate that the derivative of *tert*-butylcarbazolyl and anthracene is the most promising candidate for electronic devices due to its high hole mobility, reaching 7.6×10^{-5} cm²/(V s) at an electric field of 8×10^5 V/cm. Exploitation of a guest-host containing the *tert*-butylcarbazolyl and anthracene derivative as a host exhibiting triplet-triplet annihilation (TTA) and a fluorescent emitter resulted in an efficient hyperfluorescent OLED with a maximum external quantum efficiency of 7.1%. The OLED with such efficiency outperformed the theoretical limit of conventional fluorescence-based devices due to the utilization of triplet excitons in emission allocated to TTA upconverted excitons.

KEYWORDS: *triplet*-*triplet annihilation, OLED, hyperfluorescence, anthracene, carbazole*

INTRODUCTION

The technology of organic light emitting diodes (OLEDs) needs to solve the issue of the stability and efficiency of devices, especially those with the blue color of emission, for the further advancement in the market of displays and lighting devices.¹⁻³ Nowadays, OLED displays and lighting devices waste ca. 50% of their power because of the low efficiency of the blue fluorescent emitters currently used in OLEDs.^{4,5} In addition, blue pixels often account for ca. 50% of the total display structure, along with red and green pixels.⁶ Extrinsic factors such as encapsulation of the OLEDs, upgraded substrates, and so forth can affect the device fabrication and its operational work. They are exploited in trying to improve the stability of the diodes including those emitting blue light.¹ On the other hand, the improvement of the characteristics of organic semiconductors used in OLEDs is an important activity that may allow the improvement of the stability and efficiency of OLEDs.

When electricity is applied, singlet and triplet excitons are formed in the ratio of 1 to 3 in OLEDs due to spin statistics.^{1,7}

The utilization of triplet excitons in electroluminescence (EL) is considered for the increase in efficiency of the diodes. Several approaches have been introduced aiming to stimulate triplet exciton emission. They include phosphorescence of noble metal complexes, thermally activated delayed fluorescence (TADF), room-temperature phosphorescence (RTP) of organic emitters, and reverse intersystem crossing (RISC) via hybridized local charge transfer (HLCT) states.^{1,8–12} Although significant improvements have been made in the design and application of emitters exhibiting the above-mentioned phenomena, they all have their own limitations and require further modification. The limitations are related to the operational stability, color quality, energy consumption, cost

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efficiency, and environmental pollution.¹ Blue phosphorescent and TADF emitters developed to date are not stable enough for industrial use.¹³ The high-energy and long lifetime of excited triplet states of phosphorescent and TADF emitters are the main reasons for the limited stability of blue organic electroluminescent devices.^{14,15} Different strategies were exploited to overcome the limitations of TADF and phosphorescent emitters. For example, the control of the host morphology for boosting the stability and efficiency of deep-blue PhOLEDs and phosphor-sensitized TADF emission systems were developed.^{16,17} The deep-blue emitting devices with the external quantum efficiency of ca. 22-26% and operational lifetime significantly longer than that of the conventional deep-blue devices were obtained.^{16,17} However, the use of noble metals for such emissive complexes remains problematic from the environmental point of view.¹

Fortunately, it is possible to achieve the η_{EQE} higher than the theoretical limit of 5% of OLEDs with the conventional fluorescent emitters.¹⁸ This can be done by exploiting lowenergy excited triplet states, e.g., through triplet-triplet annihilation (TTA). TTA is a nonlinear process, i.e., yielding nonlinear increments in excitation in this case, of utilization of the triplet electronic excitation energy.^{19,20} This is considered to be one of the primary reasons for the efficiency roll-off of OLEDs.²¹ However, TTA itself can be used as a tool for increasing the efficiency of the triplet emitters by upconverting two triplet excitons and generating a singlet exciton of twice higher energy, while the other annihilating species is returned to the ground state.¹³ Depending on the alignment of the energy levels of the excited states, the recombination of the exciton can occur directly from this $2 \cdot T_1$ energy level of a single state or after relaxation to the lower singlet excited state.²² Triplet fusion provides an opportunity to increase the limit of internal quantum efficiency from 25% for OLEDs based on prompt fluorescent emitters to 62.5% for the devices based on emitters exhibiting TTA. The studies on the TTA contribution to the EQE of the OLEDs remains limited. As TTA was originally studied in detail for pyrene, the historic term for the long-lived emission arising from TTA is p-type delayed fluorescence.^{23,24} As the triplet states are involved in creating the exciton, the emission of the newly formed singlet exciton is delayed fluorescence, characterized by long lifetimes, mostly on a microsecond scale. The lifetimes are considerably longer than those of the original excitons deactivated through prompt fluorescence. The diffusion control model of the sensitizer-annihilator system or the so-called producer-promoter system is generally considered for TTA systems.^{13,25} According to this model, a molecule of the sensitizer is photoexcited, populating triplet excited states through intersystem crossing (ISC) from singlet excited states. Subsequently, hopping from the sensitizer to a molecule of the annihilator occurs through triplet-triplet energy transfer (TTET) by the Dexter exchange mechanism, populating the triplet excited states of the annihilator.^{13,25} TTA is initiated in the intermolecular interaction of two annihilator molecules once a sufficient population of the annihilators is reached, forcing an encounter between them. Intramolecular TTA in the case of sensitizer-annihilator systems has also been reported.¹⁴ Both TTET and TTA are diffusion-mediated processes relying on the concentrations of the compounds. A single molecule exhibiting delayed fluorescence originated from TTA without approaching the specific intermolecular interactions of two compounds, such as in sensitizerannihilator systems, is of great demand. It can potentially allow one to simplify the device fabrication by not using a sensitizer. The significant energy losses occur during ISC in a sensitizer and TTET from a sensitizer to an annihilator.¹⁴ Predictably, the shortcomings of TTA-based OLEDs can be addressed by developing new functional materials.

Anthracene-based emitters exhibiting TTA-related delayed fluorescence have attracted great interest over the last years.^{26–29} Some of them have a carbazole moiety as a donor.^{30,31} They are primarily used as emitters in OLEDs.³² A relatively new method for efficient harvesting of triplet excitons in OLEDs is based on hyperfluorescence.^{33,34} TADF molecules are typically used as cohosts in organic hyperfluorescence systems.³⁵ The hyperfluorescence approach allows us to achieve higher internal quantum efficiencies (IQEs) and EQEs for OLEDs than those for the devices based on prompt fluorescence.³⁶ Hyperfluorescence-based systems allow us to reach higher color purity and operational stability for OLEDs than for TADF systems.^{37,38} In contrast to conventional TADF-based hyperfluorescence, our investigation partly aimed to explore the applicability of TTA hosts in hyperfluorescent OLEDs.

In this work, we designed and synthesized the derivatives of an anthracene core exhibiting blue TTA emission and studied them as hosts in hyperfluorescent guest-host systems. A large planar conjugated system of anthracene was exploited to ensure molecular packing, stabilizing triplet excitons and inducing intermolecular interactions mediated by carbazole donors. Such interactions resulted in TTA. Molecular packing of anthracene derivatives is known to cause aggregation-caused quenching.³⁹ The designed structures enable adjustment of the steric hindrance.⁴⁰ The carbazole moiety is selected as an electron donor unit because of its known capability of improving thermal stability and charge transport and tuning the energy levels of triplet excited states.⁴¹ The molecular packing in the films of the two compounds from the series is affected by alkoxy groups attached to carbazole moieties. The attachment of alkoxy groups alters the energy levels of molecular orbitals, improving the thermal stability of the compounds and charge balance at recombination sites. These effects manifest due to hydrogen bonding of the oxygen atoms of alkoxy groups and the hydrogen atoms of the interacting molecules.¹³ The attachment of the tert-butyl group to the carbazole moiety was found to be a pathway for minimization of the loss of energy of triplet excitons via nonradiative deactivation.⁴² In this work, the theoretical and experimental analysis of the derivatives of anthracene and carbazole was performed to detect the delayed fluorescence and confirm its TTA origin. The derivative of tert-butylcarbazole and anthracene was successfully utilized as both an emitter and a host for blue-emitting OLEDs. Using the new TTA compound, blue TTA-based doping-free and TTA-assisted hyperfluorescent OLEDs were fabricated with maximum EQEs of 5.9 and 7.1%, respectively.

EXPERIMENTAL SECTION

Unless otherwise stated, all reagents were purchased from commercial suppliers and used without further purification. Thin layer chromatography (TLC) was performed using MERCK Silica gel 60 F254 plates and visualized by UV (254 nm) fluorescence. ZEOCHEM silica gel (ZEOprep 60/35–70 μ m—SI23501) was used for column chromatography. ¹H and ¹³CNMR spectra were recorded on a Bruker 400 spectrometer at 400 and 101 MHz,

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Scheme 1. Synthesis of Carbazolylphenyl Anthracenylbenzonitriles 7a-c^a



"Reaction conditions: (a) excess of sodium methanolate in DMF or sodium methoxyethanolate in methoxyethanol, heating; (b) 4-bromofluorobenzene (1.1 equiv), Cs_2CO_3 (5.0 equiv), NMP, 150 °C, 48 h; (c) *n*-BuLi (1.2 equiv), Me_3SnCl (1.2 equiv), THF, -78 °C; (d) (4-cyanophenyl)boronic acid (1.0 equiv); K_2CO_3 (8.0 equiv), Pd(PPh₃)₄ (0.02 equiv), H₂O/toluene/methoxyethanol, 90 °C, 2 h; and (e) 6, Pd(PPh₃)₄ (0.05 equiv), AsPh₃ (0.05 equiv), xylene, 120 °C, 12 h.

respectively, at 298 K in CDCl₃. The ¹H chemical shifts are given relative to the residual CHCl₃ signal (7.26 ppm), ¹³C—relative to CDCl₃ (77.16 ppm). Reagents were purchased from regular vendors, e.g., BLD Pharm, ABCR, TCI Europe, and ACROS.

All density functional theory (DFT)-based computational calculations are done using the Gaussian 16 program,⁴³ and threedimensional molecular geometries are drawn and viewed by using GaussView 6. The geometries of An-tCZ, An-MCz, and An-ECz are optimized at the ground level using the Becke 3-parameters Lee– Yang–Perdew (B3LYP) hybrid functional⁴⁴ and 6-31G(d,p) basis set. The impact of the solvent is also computed using the integral equation formalism polarizable continuum model (IEFPCM) for DFT calculations. Reorganization energy (RE) estimations for electron (λ_e) and hole (λ_h) mobilities were also done at B3LYP/6-31G(d,p) for potential analysis of charge transfer properties of compounds. Density of states (DOS) calculations were performed at the B3LYP/ 6-31G(d,p) level, and plots were generated using PyMOlyze 1.1 software.

Absorption spectra were recorded by an Avantes AvaSpec-2048XL spectrometer. Emission spectra and photoluminescence (PL) quantum yields (Φ) were determined using an Edinburgh Instruments' FLS980 fluorescence spectrometer. Φ was estimated using an integral sphere by an absolute method. PL decay curves and transient PL spectra were measured using FLS980 equipped by the 374 nm laser PicoQuant LDH-D-C-375 and the Edinburgh Instruments uF920H microsecond lamp, for which 350 nm was chosen as the wavelength of photoexcitation. A Pfeiffer HiCUBE pump and an Optistat DN2 cryostat were utilized for the measurement at deoxygenated conditions and low temperatures.

We utilized the highly reliable time-of-flight (TOF) method to precisely characterize charge transport in organic materials **An-tBCz**,

An-MCz, and An-ECz for accurate determination of hole and electron mobilities in vacuum-deposited layers of the investigated compounds. A more than 1 μ m thick organic layer of An-tBCz, An-MCz, and An-ECz as the active medium, indium-tin oxide (ITO) as the bottom electrode, and aluminum as the top electrode were used in our TOF experiments. The layers were kept pure and intact by carrying out the deposition process under a vacuum of 2 \times 10⁻⁶ mbar. In our experimental setup, we utilized an EKSPLA laser with a wavelength of 355 nm as the excitation source to generate charge carriers within the organic layer. By applying various positive and negative external voltages to the samples using the Keithley precision 6517B electrometer, we investigated the hole and electron transport under different electric fields. We used the TDS 3032C oscilloscope made by Tektronix to measure the transit time $(t_{\rm tr})$ of charge carriers. By recording the photocurrent transients of either holes or electrons for layers of An-tBCz, An-MCz, and An-ECz, we were able to estimate the charge mobilities (μ) using the formula $\mu = d^2/(V \times t_{tr})$, where d represents the thickness of the organic layer and V corresponds to the applied voltage over the sample. Thicknesses (d) of organic layers of An-tBCz, An-MCz, and An-ECz were determined by the profilometer Profilm3D (Figure S11).

The process of the bottom-emission OLED fabrication used an indium tin oxide (ITO) substrate to be the anode that was treated by oxygen plasma to clean its surface and also increase its work function (from 4.9 to 5.1 eV) to reduce the energy barrier at the anode/ organic layer interface. The organic layers and inorganic cathode were deposited by using a multisource evaporator with an ultrahigh vacuum. For device encapsulation, all devices were encapsulated with a transparent cover glass and sealed with ultraviolet glue inside a glovebox (N₂ ~99.95%). The electrical and optical characteristics of devices were measured by a L-J-V system consisting of a



Figure 1. DSC curves of An-tBCz (a), An-MCz (b), and An-ECz (c) and TGA curves of the compounds (d) recorded in a nitrogen atmosphere and the scan rate of 20 $^{\circ}$ C/min.

multisource meter (Keithley 2400) and a spectrometer (Minolta CS1000), such as current density versus driving voltage (J-V), luminance versus driving voltage (L-V), emission spectrum, color coordinates, current efficiency ($\eta_{\rm CE}$), power efficiency ($\eta_{\rm PE}$), external quantum efficiency ($\eta_{\rm EQE}$), and operational lifetime. The further carrier and exciton dynamics were analyzed by using a transient electroluminescence (TrEL) system, whose setup consisted of a waveform function generator (Agilent 335011B) to drive the OLED and a photomultiplier (Hamamatsu, H6780-20) as well as an oscilloscope (Tektronix, TSB2202B) to collect and record the optical signal form the OLED. Some of the L-J dependences for the evaluation of slopes were recorded using a calibrated PH100-Si-HA-D0 photodiode, a Keithley 2400C SourceMeter, a 11S-LINK Power and Energy Monitor, and a 6517B electrometer.

RESULTS AND DISCUSSION

Synthesis. The preparation of the desired carbazolyl phenyl anthracenyl benzonitriles and **An-MCz**, **An-ECz**, and **An-tBCz** was started with the treatment of 3,6-dibromocarbazole (1) with sodium methanolate and methoxyethanolate, yielding the corresponding 3,6-dimethoxycarbazole (2a) and 3,6-bis(2-methoxyethoxy)-9*H*-carbazole (2b) in 95 and 97%, respectively (Scheme 1). *N*-Bromophenylcarbazoles 3a-c were obtained from the reaction of 2a-c with 4-bromo-fluorobenzene in the presence of an excess of cesium carbonate

in *N*-methylpyrollidinone (NMP). We decided to use the Stille coupling protocol for the binding of the carbazolylpenyl moiety to the anthracene fragment as the use of arylboronic acids was not sufficient. Derivatives 3a-c were converted to the corresponding stannanes 4a-c. It is important that the derivatives 4a-c were not purified and used as raw material in the next step as trimethyltin derivatives are very harmful to human health. 4-(10-Bromoanthracen-9-yl)benzonitrile (6) was prepared from (4-cyanophenyl)boronic acid and 9,10dibromoanthracene (5) in the presence of potassium carbonate and a catalytic amount of tetrakis-(triphenylphosphine)palladium.⁴⁵ It should be noted that the boronic acid must be added in portions; otherwise, the yield is low. As a result, compound 6 was isolated in 61% yield. Finally, the desired products An-MCz, An-ECz, and An-tBCz were obtained by the Stille coupling reaction of 4a-c with bromoanthracene 6. The coupling reactions were carried out in the presence of the palladium(0) catalyst $[(Ph_3P)_4Pd]$ and triphenylphosphine as the ligand.⁴

Thermal Properties. Differential scanning calorimetry (DSC) was employed to investigate the thermal transitions such as melting and glass transitions. The DSC curves are shown in Figure 1. The thermal characteristics of the target derivatives (An-tBCz, An-MCz, and An-ECz) are listed in

Table 1. The DSC traces of the initial heating scans verified the crystalline character of all of the target derivatives. Well-

Table 1. Thermal Characteristics of Compounds An-tBCz, An-MCz, and An-ECz

compound	$T_{m'} (^{\circ}C)^{a} (1st heating s)$	$T_{g'}$ (°C) ^b (2nd heating s)	$T_{cr'} (^{\circ}C)^{b}$ (cooling)	T_{d} (°C)
An-tBCz	398		301	387
An-MCz	331		204	399
An-ECz	210	99		407

^{*a*}Melting temperature at the scan rate of 10 °C/min, N₂ atmosphere. ^{*b*}Glass transition temperature. ^{*c*}5% weight loss temperature at the scan rate of 20 °C/min, N₂ atmosphere.

defined endothermic melting signals at the temperatures ranging from 210 to 398 $^\circ C$ were observed. The highest $T_{\rm m}$ values were detected for tert-butyl- and methoxy-substituted derivatives (An-tBCz and An-MCz). We presume that the presence of sterically smaller groups can affect the molecular packing of substances, which can lead to higher melting points as more energy is required for the solid-to-liquid transition to overcome the intermolecular forces between molecules. During the DSC cooling scans, notable exothermic crystallization peaks were observed for An-tBCz and An-MCz. Specifically, An-tBCz exhibited a crystallization peak at 301 °C, and An-MCz showed a peak at 204 °C. No such crystallization transition was identified for An-ECz. Upon analysis of the DSC second heating scans, distinct observations from AntBCz and An-MCz were made for An-ECz. It presents a stable molecular glass with a transition temperature of 99 °C. In the case of An-tBCz and An-MCz second heating DSC curves, their crystalline character was reaffirmed with peaks corresponding to the temperatures observed during the first heating scan.

Thermogravimetric analysis (TGA) was used to investigate the thermal stability of the target compounds. The TGA curves of the compounds are shown in Figure 1d. All anthracene derivatives (An-tBCz, An-MCz, and An-ECz) exhibited high thermostability under heat in an inert atmosphere. The 5% weight loss temperature (T_d) ranged from 387 to 407 °C. The derivative enriched with methoxyethoxy groups (An-ECz) showed the highest T_d . The elevated T_d values of An-MCz and An-ECz can also be attributed to the augmented intra-molecular forces.

Electrochemical Properties. The electrochemical properties of the DCM solutions of compounds An-tBCz, An-MCz, and An-ECz were assessed by cyclic voltammetry at a 100 mV/ s scan rate using ferrocene as an inner standard (Figure 2). The studied compounds having tert-butyl (An-tBCz), methoxy (An-MCz), or methoxyethoxy (An-ECz) groups linked to C-3 and C-6 positions of carbazole moieties exhibited a doublewaved reversible oxidation-reduction pattern between 0.00 and 0.97 V (over three repeated scans). Oxidation onsets were observed at 0.68, 0.45, and 0.46 V (vs Fc/Fc+), the peaks of the first waves were recorded at 0.78, 0.55, and 0.56 V, and those of the second waves were observed at 0.97, 0.96, and 0.98 V. No reduction waves were observed down to -2.0 V. The ionization potentials (IP_{CV}) of the target compounds were derived using the following equation: IP_{cv} (eV) = $-E_{ox}$ (V) – 4.8.⁴⁷ The calculated IP_{CV} values for the new derivatives fell in the range of 5.25-5.48 eV. Compared to the tert-butylated derivative (An-tBCz), alkoxy group-containing compounds (An-MCz and An-ECz) showed lower IP_{CV} values by 0.22-0.23 eV. These results correlate well with previous findings.⁴⁸

Ionization potentials of the solid samples of the compounds (IP_{PE}) were measured by photoelectron emission spectroscopy. The electron photoemission spectra are shown in Figure 2b. The IP_{PE} values are collected in Table 2. These values were derived from the linear segments of the spectra, specifically at the points where the photocurrent was zero.

The ionization energy was altered by the interaction of ionized molecules with the solid, polarizable surroundings, affecting the polarization energy. The IP_{PE} values exceeded the IP_{CV} values (Table 2), likely because of enhanced intermolecular interactions (hydrogen bonding). For anthracene derivatives (An-MCz and An-ECz), which contain alkoxy groups, the IP_{PE} values were 0.1–0.2 eV lower than the IP_{PE} value of the compound with the *tert*-butylated carbazole moiety (An-tBCz).



Figure 2. Cyclic voltammetry curves of DCM solutions (a) and photoelectron emission spectra of the layers (b) of An-tBCz, An-MCz, and An-ECz.

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Table 2. Electrochemical Characteristics of Compounds An-tBCz, An-MCz, and An-EC z^a

compound	$E_{\rm ons}$ (V)	$E_{\text{ox,pa}} (V)^{b}$	$E_{\text{ox,pc}}$ (V) ^b	$IP_{cv} (eV)^{c}$	$E_{g} (eV)^{d}$	$\mathrm{EA}_{\mathrm{PE}}~(\mathrm{eV})^{e_{i}f}$	$IP_{PE} (eV)^{f}$	LUMO (eV) ^g	HOMO (eV) ^g	$E_{\rm gap}~({\rm eV})^{\rm g}$
AN-tBCz	0.68	0.78/0.97	0.70/0.89	5.55	2.92	2.51	5.43	1.97	5.27	3.29
AN-MCz	0.45	0.55/0.96	0.48/0.88	5.23	2.89	2.5	5.39	1.97	4.95	2.98
AN-ECz	0.46	0.56/0.98	0.49/0.86	5.24	2.79	2.68	5.47	1.96	5.01	3.05

^{*a*}Data values were calibrated with the ferrocene (Fc) standard. ${}^{b}E_{ox}{}^{pc}$, $E_{ox}{}^{pc}$ —peak potentials corresponding to successive molecular first and second oxidations, respectively. ${}^{c}\Pi_{cv} = -1.4E_{onset,ox}$ (V) – 4.6. d Estimated from the onset of absorption spectra of the films. e Calculated using E_{g} values. f Estimated from photoelectron emission spectra in air. g Evaluated from theoretical calculations.

Table 3. Bond Angle 1 (θ_1) and Bond Angle 2 (θ_2), REs for Electron and Hole Transport, and Dipole Moments (D) in the Gas State and Solutions of An-TBCz, An-MCz, and An-ECz

compound	$\theta_1 \; ({ m deg})$	$\theta_2 \; (deg)$	$\lambda_{\rm e}~({\rm eV})$	$\lambda_{ m h}~({ m eV})$	D (gas)	D (toluene)	D (THF)
An-tBCz	85.5	52.5	0.5329	0.1838	4.13	4.48	4.67
An-MCz	79.4	51.7	0.4796	0.1898	4.79	5.09	5.25
An-ECz	78.9	51.6	0.4688	0.2004	5.34	5.65	5.81



a)



Figure 3. Optimized geometries (a) and molecular orbitals with energy levels of An-tBCz, An-MCz, and An-ECz (b) at B3LYP/6-31G(d,p).

Theoretical Calculations. The dihedral angles between anthracenyl benzonitrile and the phenyl present in the core (dihedral angle 1, θ_1) and between the carbazole moiety and the phenyl present in the core (dihedral angle 2, θ_2) were calculated. The values are given in Table 3. θ_1 is wider than θ_2 for all the studied compounds, indicating that the donor and acceptor parts of the molecules are nonplanar with the possibility of charge separation between the donor and acceptor (Figure 3a). The highest occupied and lowest unoccupied molecular orbitals (HOMO and LUMO, respectively), together with their respective energy levels and theoretical band gaps (E_{gap}), are shown in Figure 3b and Table 2.

Carbazole and its *tert*-butyl substituents in An-tBCz, carbazole and its methoxy substituents in An-MCz, and carbazole and part of its methoxyethoxy substituents in An-ECz are the main sites of charge density existence in the HOMO, deciphered as the donor part of the molecules. Since the dihedral angles between the carbazole moieties and the

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compound	λ_{\max} (nm)	Φ (%)	λ_{\max} (nm)	Φ (%)	S_1^a (eV)	T_1 (eV)	$\Delta E_{\rm ST}$ (eV)	S_1 (eV)	$T_1 (eV)$	$\Delta E_{\rm ST}$ (eV)
	deox.	tol.	filn	ı		film, Argon, 77	ΥK		theor.	
An-tBCz	439	76	454	17		no data	ca. 1	2.93	1.74	1.20
An-MCz	452	95	480	24	2.93	1.92	1.01	2.64	1.73	0.91
An-ECz	454	99	493	37	2.86	1.89	0.97	2.70	1.73	0.97
^{<i>a</i>1} CT.										

Table 4. Major Photophysical Characteristics of the Compounds



Figure 4. Energy level diagram of the first four singlet and triplet states, oscillator strength (f), and spin-orbit coupling matrix of An-TBCz, An-MCz, and An-ECz.

phenyl group in the centers of the molecules are not very high, the charge density is also placed on the central phenyl groups in the HOMO state. The charge density is situated on anthracenyl benzonitrile in the LUMO of all molecules studied; anthracenyl benzonitrile moieties are identified as the acceptor parts of the molecules due to the existence of highly electronegative nitrile substituents at the terminal parts. The charge separation in the HOMO and LUMO can be clearly evaluated from high θ_1 and the phenyl group in the core of the molecules acting as a bridge between the substituted carbazole moieties as the donor parts and anthracenyl benzonitrile moieties as the acceptors. An-tBCZ has the most stable HOMO since it is characterized by the lowest HOMO energy (-5.27 eV).⁴⁹ An-MCz and An-ECz have comparable stability of the HOMO because of their comparable HOMO energy levels (-4.95 and 5.01 eV, respectively). The calculated HOMO–LUMO E_{gap} (Table 2) corresponds to the optical band gap E_{g} calculated from the onset of the absorption spectra of toluene solutions to a great extent for every compound.

Time-dependent DFT (TD-DFT) calculations were also performed at B3LYP/6-31G(d,p) up to 30 excited states for the investigated compounds in the gaseous phase. The impact of solvent was also computed using the integral equation formalism polarizable continuum model (IEFPCM). The computed absorption spectra of An-tBCz, An-MCz, and An-**ECz** in the gas phase and toluene and tetrahydrofuran (THF) solutions along with the comparison of empirical absorption spectra of these compounds are shown in Figure S7. The TD-DFT results for the compounds in the gaseous phase are given in Table S1, and those for toluene solutions are given in Table S2. The theoretical absorption trends of compounds in the gas phase and in both solutions are potentially correlated with the experimental absorption spectra. For example, in the experimental absorption spectrum of the dilute solutions of the compounds in toluene, the first peak of An-tBCz from tertbutylated carbazole at 296 nm corresponds to the computed absorption band for **An-tBCz**, with the transition of $S_0 \rightarrow S_8$ at the wavelength of 306 nm and oscillator strength (f) of 0.322. In the empirical absorption spectrum of An-MCz, the peak of

the methoxy-substituted carbazolyl group was found at 310 nm. In the case of An-ECz, the peak of the methoxyethoxysubstituted carbazole moiety was observed at 311 nm. The S₀ \rightarrow S₈ transition in the theoretical spectrum of An-MCz corresponds to the wavelength of 324 nm and f of 0.28. The S_0 \rightarrow S₈ transition in the case of **An-ECz** is related to the intense peak at 319 nm with an f value of 3.88. The experimental absorption trend of multiple peaks from anthracenyl benzonitrile remains almost the same for all the molecules (An-tBCz, An-MCz, and An-ECz). The second intensive peaks observed in the computed absorption spectra correspond to transition $S_0 \rightarrow S_2$ (167 \rightarrow 169) manifesting at 396 nm with an f of 0.26 for An-tBCz, to transition $S_0 \rightarrow S_2$ (151 \rightarrow 153) manifesting at 401 nm with an f of 0.28 for An-MCz, and to transition $S_0 \rightarrow S_2$ (175 \rightarrow 177) manifesting at 400 nm with an f of 0.28 for An-ECz. It illustrates good agreement of theoretical and empirical absorption aspects. The overall absorption trends for all of the compounds remained the same for toluene and THF solutions. A slight red shift (Figure S7) compared to the signature band of carbazole was also observed in the computed first absorption peak from the carbazole moiety of the molecules in the gas phase, which may be caused by the self-polarity and self-assembly of the carbazole-based moiety that causes self-excitation.^{50,51} The theoretical estimations of S₁ and T₁ energies corresponding to the empirical singlet and triplet state energies of An-MCz and An-ECz calculated at 77 K with excitation at 300 nm support the potential charge transfer energies and the existence of an infrared peak (Tables 4 and S1). The computed S_1 energy of **An-tBCz** (2.93 eV) illustrates the charge transfer energy of the molecule. The theoretical T₁ energy of 1.74 eV supports the potential existence of vibronic sublevel peak in the spectrum of **An-tBCz**. The energies of the first four singlet $(S_1 - S_4)$ and first four triplet states (T_1-T_4) , along with the calculated spin-orbit interaction (H_{so}) between them, for An-TBCz, An-MCz, and An-ECz are illustrated in Figure 4. Spin-orbit coupling matrix elements (SOCMEs) for S_1-S_4 with T_1-T_4 were computed in detail (Table S3). They illustrate an extremely small SOCME between these states (less than 1 cm⁻¹). The observation of such weak SOCMEs indicates the



Figure 5. Absorption and PL spectra (a) of toluene and THF solutions and of the films of the compounds recorded at room temperature and PL decay curves (b) of the film of An-ECz recorded in vacuum at room temperature. PL decay curves were recorded at an emission wavelength of 493 nm in ns and ms ranges using laser PicoQuint and xenon lamp μ F2 as the excitation sources at an excitation wavelength of 374 nm.

least probability of RISC and ISC. However, it implies a heightened likelihood of TTA.

Applying the Marcus theory to the analysis of the RE allows one to probe the degree of charge mobility on intermolecular and intramolecular scales.⁵² Internal and external REs combine to form the total RE. In external RE, polarization changes occur during charge transfer, and the external environment undergoes rapid variations, while the structural variation of a molecule is the key factor in internal RE.⁵³ We focused only on the internal RE for the purpose of our study because external RE cannot be computed from various external aspects. The numerical values were calculated using eqs 1 and 2 (Table 3)^{54,55}

$$\lambda_{\rm h} = [E_{\rm +}^0 - E_{\rm 0}] + [E_{\rm 0}^+ - E_{\rm +}] \tag{1}$$

$$\lambda_{\rm e} = [E_{-}^0 - E_0] + [E_{0}^- - E_{-}] \tag{2}$$

The optimized neutral molecules with energies of the cation and anion are E_0^- and E_0^+ , respectively. The anions and cations, optimized with anion and cation energies, are E_{-} and E_{+} , respectively. The optimized anion and cation with neutral energies are $\vec{E_+}^0$ and $\vec{E_-}^0$, respectively. The RE studies show that the investigated molecules exhibit highly efficient hole transport compared with electron transport. An-tBCz with the smallest λ_h possessing the highest hole mobility is due to its alkyl substituted carbazole donor unit. An-MCz with a methoxy-substituted carbazole donor moiety was characterized by the second highest hole mobility. An-ECz showed the lowest hole mobility among the investigated compounds. These observations show that the attachment of methoxy and methoxyethoxy substituents to the carbazole moiety results in the slightly decreasing hole mobilities of the derivatives of carbazole and anthracene. An-ECz containing a methoxyethoxy-substituted carbazole unit exhibited the best electron mobility. The dipole moments calculated for the excited states in the gas phase and toluene and THF solutions showed a slight increase going from the gas phase to toluene solution and a slight increase for THF solution compared to that of toluene solution (Table 3). This illustrates the polarization impact of polar solvents. This also supports the phenomenon of solvatochromism for An-MCz and An-ECz owing to the red shift in their emission in THF as compared to the emission in toluene. The dipole moment of An-tBCz is the lowest in all environments. The dipole moments of alkoxy derivatives (An-MCz and An-ECz) are considerably higher.

DOS analysis was performed to better understand the participation of different units of the molecules (donor, bridge,

and acceptor) in the HOMO and LUMO.⁵⁶ Determining the configurations of Frontier molecular orbitals (FMOs) in relation to Mulliken charge density relies heavily on DOS calculations.⁵⁷ To understand the participation of several molecular units in the FMOs, we regarded the tert-butyl-, methoxy-, and methoxyethoxy-substituted carbazole fragments in An-tBCz, An-MCz, and An-ECz, respectively, as the donor moieties. The phenyl ring in the core as the bridge and anthracenyl benzonitrile are regarded as the acceptors. In the DOS plots of An-tBCz, An-MCz, and An-ECz (Figure S8), the x-axis represents the energy, the y-axis represents the relative intensity, and the black, red, and green lines show the levels of participation of donor, bridge, and acceptor units in FMOs, respectively. The total participation is shown by the blue line. The numerical participation information is given in Table S4. The trend of the participation of the different units in the FMOs is almost the same for all of the molecules investigated. DOS analysis indicated a level of donor at ca. 90%, a level of bridge up to 10%, and a slight involvement of the acceptor of ca. 1% in the HOMO. In the LUMO, a major participation of 98.6-99% is shown by the acceptor unit, a very slight involvement of that of the bridge, and negligible participation by the donor of no more than 0.1%. DOS analysis provides a clear evaluation of θ_1 and θ_2 , as well as the presence of charge density in the FMOs, as shown in Figure 3a, via the sequential operation of the phenyl unit as a bridge.

Photophysical Properties. Absorption spectra of toluene solutions of the compounds (Figure 5a) consist of the signature absorption peaks of carbazole at a wavelength shorter than 350 nm and vibronic multipeak bands of anthracene in the longer wavelength range.58,59 The carbazole-related absorption band of the low-energy $\pi - \pi^*$ transition around 300 nm is bathochromically shifted for An-MCz and An-ECz when compared to that for An-tBCz due to the attachments of alkoxy substituents to the carbazole moieties notably increasing π -conjugation.⁶⁰ The anthracenebased vibronic bands are located almost at identical wavelengths for all the investigated compounds. These bands are red-shifted by ca. 25 nm from the previously reported position for anthracene absorbance. This observation is explained by the addition of a benzonitrile moiety to the acceptor, expanding π -conjugation.⁶¹ The absorption spectra of the films are broader and red-shifted in comparison to those of the corresponding toluene solutions because of the enhanced intermolecular interactions in the solid state.

PL spectra contain single peaks and show the occurrence of positive solvatochromism for An-MCz and An-ECz. It

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Figure 6. TOF signals (a) for holes recorded for the vacuum-deposited film of An-tBCz at different electric fields and hole mobilities (μ_h) of An-tBCz, An-MCz, and An-ECz (b) plotted as a function of electric fields according to the Poole–Frenkel relationship.

manifests by the red shift of emission of the solution when the nonpolar toluene is changed by the polar THF. The apparent solvatochromic effect highlights the intramolecular charge transfer (CT) between the alkoxy-substituted carbazole and 4-(anthracene-9-yl)benzonitrile. Thus, the emission of An-MCz and An-ECz at room temperature is associated with radiative deactivation of excitons from the ¹CT state. The ¹CT peak is shifted to the red spectral range for An-MCz and An-ECz when compared to the emission of An-tBCz (Figures 5a and S9b) suggesting ¹LE emission of the local excited (LE) state of anthracene for An-tBCz. The peaks of PL bands in the films of the compounds are situated in between the peaks of the PL bands of toluene and THF solutions, highlighting the selfpolarity of the layers, which are less polar than THF. The highest Φ values were observed for deoxygenated toluene solutions and the films of compound An-ECz containing methoxyethoxy-substituted carbazole fragments. They were found to be of 99 and 37%, respectively (Table 4). Compound An-MCz having methoxy-substituted carbazolyl groups showed slightly lower values of Φ , while the solutions and films of An-tBCz showed the least efficient emission. The significantly lower Φ shown by the solid films can be explained in terms of aggregation-caused quenching or PL quenching by interception of the triplet electronic excitation energy by collisional interactions of the molecules and oxygen.⁶² The utilization of triplet excited states in emissive processes is confirmed by the PL decay curves of the films of An-MCz and An-ECz (Table S5 and Figures 5b and S9a). The films of all of the investigated compounds have sub-10 ns lifetime components of the PL decay curves assigned to prompt fluorescence. Additionally, PL decay curves of An-MCz and An-ECz have components with the lifetimes of ca. 30 ns and 0.15 ms. The removal of oxygen did not change the spectral profile of the emission of the films at room temperature. Thus, the spectral contribution of the triplet energy is from the same excited states as those for prompt fluorescence. This observation allows us to exclude RTP from the origin of the emission. Consequently, the long-lived PL of An-MCz and An-ECz is attributed to delayed fluorescence.

Time-resolved PL spectra were recorded for the films of the compounds at 77 K (Figure S9d). An-tBCz exhibited a double

peak PL band that cannot be interpreted indisputably with a cutoff energy of 2.94 eV assigned to ¹LE. The origin of the second subpeak can be in the presence of vibronic sublevels, emission of the ¹CT state at a lower energy than for the ¹LE or the DF energized by TTA. The PL spectrum of the film of AntBCz recorded with a delay of 0.1 ms is not very intensive to correctly evaluate the onset energy and the position of the peaks that would help make an appropriate description of its nature. An-MCz has a ¹CT peak at 2.92 eV. Both An-MCz and An-ECz exhibit an infrared peak at ca. 730 nm, appearing if excited at 300 nm but not at 350 nm. The cutoff energy of the band fits the theoretical prediction of the energy level position for T_1 (Table 4). The existence of the emission with a long lifetime is evident from the spectrum of the film of An-ECz recorded at 77 K with the delay. The intensity of the band is high when excited at 300 nm. At an excitation wavelength of 350 nm, the anthracene moiety is excited directly, causing enhancement of TTA. Consequently, the electronic excitation energy from T_1 is used in TTA and is not deactivated through radiative recombination via phosphorescence. The extension of the donor in the structure resulted in a lowering of the T_1 energy level from 1.92 for An-MCz to 1.89 eV for An-ECz. The energy level of T_1 for **An-tBCz** is assumed to be close to those of other compounds of the series as the state is identified as of LE origin. The PL spectra recorded without delay exhibit the difference in the energy levels of the major low-energy PL peak for An-ECz when excited at different excitation wavelengths. The peaks are assigned to ¹LE and ¹CT, with estimated cutoff energy levels of 3.01 and 2.86 eV, respectively. The spectrum recorded with the excitation wavelength of 300 nm has a ¹CT peak, which is in total correspondence with its location when compared to the spectra of An-MCz recorded both at 77 K and at room temperature (Figure S9). The observed spectral behavior is determined by TTA. The discussed enhancement of TTA when the anthracene is excited directly provides energy to the ¹LE state, which is higher than that of ¹CT and closer to the energy of $2 \cdot T_1$ (Table 1 and Figure S9b). Thus, the ¹LE emission of the film of An-ECz is delayed fluorescence caused by TTA. It is observable in the PL spectra recorded with the delay. The bands of longlived emission in these spectra correlate with the position of



Figure 7. (a) Device structure and energy levels of each layer, (b) J-V-L curves, (c) η_{CE} , η_{PE} , and η_{EQE} vs L curves, and (d) EL spectra and 1931 CIE color coordinates recorded at 5 V of OLEDs with the EML of An-tBCz and 3 and 15% concentrations of DPaNIF in An-tBCz.

¹LE. The film of **An-TBCz** does not exhibit any peak of phosphorescence (Figure S9d). No long-lifetime component (in the millisecond range) is observed in the PL decay curves (Figure S9a). These observations are interpreted as a suppressed accumulation of triplet energy on T_1 needed for both phosphorescence and TTA, meaning that the main path of deactivation of the T_1 state is nonradiative conversion to the ground state. The values of the energy of the excited states estimated from experimental data and theoretical calculations are in good agreement (Table 4).

Charge Transport Properties. The TOF method allows the selective measurement of transit times (t_{tr}) of holes or electrons in thick semiconductor layers by applying the positive or negative voltages (V) to the optically transparent electrode.⁶³ We applied TOF for vacuum-deposited layers of An-tBCz, An-MCz, and An-ECz using a sample configuration of indium tin oxide (ITO)/thick layer/Al (Figures 6 and S10). The *d* values of organic layers of An-tBCz, An-MCz, and An-ECz were determined by the profilometer Profilm3D (Figure S11). The high dispersity of hole transport was observed for layers of all the studied compounds. The $t_{\rm tr}$ values were identifiable at the cross point of two lines (shown by the arrows) by analyzing the log-log plots of the TOF signals (Figures 6a and S11). As can be expected for organic semiconductors, holes in An-tBCz exhibited smaller t_{tr} values at lower electric fields (E), while faster hole transport was

detected at higher E (Figure 6a). No electron transport was detected in the layers of An-tBCz, An-MCz, and An-ECz (Figure S10).

Collecting t_{tr} values at the different *E*, hole mobilities (μ_h) were calculated for the layers of An-tBCz, An-MCz, and An-ECz using the formula $\mu_{\rm h} = d^2/(V \times t_{\rm tr})$. Figure 6b shows plots of $\mu_{\rm h}$ as a function of electric fields in accordance with the Poole–Frenkel relationship $\mu_{\rm h} = \mu_{\rm 0h} \exp \beta E^{1/2}$. Here, $\mu_{\rm 0h}$ and eta have a common meaning of $\mu_{
m h}$ at zero electric field and Poole-Frenkel electric field dependence, respectively. For AntBCz and An-MCz, μ_{0h} of 4.09 \times 10⁻⁸ and 2.79 \times 10⁻⁹ cm² $V^{-1} s^{-1}$ and β of 8.33 × 10⁻³ and 10.1 × 10⁻³ cm^{1/2} V^{-1/2}, respectively, were obtained by fitting using the Poole-Frenkel formula (Figure 6b). An-tBCz showed the highest $\mu_{\rm h}$ of 3.17 × 10^{-5} cm² V⁻¹ s⁻¹ at an E of 6.4 × 10^{5} V·cm⁻¹. Meanwhile, at the same *E* value, **An-MCz** showed a $\mu_{\rm h}$ of 1.6×10^{-5} cm² V⁻¹ s⁻¹ and An-ECz showed 8.84 \times 10⁻⁶ cm² V⁻¹ s⁻¹. The differences of hole mobility parameters of the compounds could be explained by the different molecular packing causing different HOMO-HOMO overlapping and different energetic disorder parameters. This statement is in good agreement with the theoretical predictions described above showing the lowest $\lambda_{\rm h}$ of 0.1838 eV, thus the best hole mobility for An-tBCz (Table 3). The TOF measurements prove that An-tBCz is the most potential candidate for use in electronic devices.

Table 5. Characteristics of Blue TTA-Based OLEDs with the EML of Pure An-tBCz and of Its 3 and 15% Molecular Mixtures with DPaNIF

EML	$V_{\rm ON}^{a}$ (V)	$\eta_{\rm CE}^{\ \ b} ({\rm cd} \cdot {\rm A}^{-1})$	$\eta_{\mathrm{PE}}^{}b}~(\mathrm{lm}{\cdot}\mathrm{W}^{-1})$	η_{EQE}^{b} (%)	L at 9 V (cd·m ⁻²)	$\lambda_{\mathrm{peak}}~(\mathrm{nm})$	1931 CIE _{x,y}	fwhm (nm)
		D	oping-Free EML:	ГTA Emitter	An-tBCz			
An-tBCz	3.7/2.9	4.8/4.5	4.2/2.7	5.9/5.6	5578	458	(0.143, 0.120)	60
		TTA-Assisted	Hyperfluorescent	EML: DPaNI	F (x wt %): An-tBCz			
An-tBCz + 3% of DPaNIF	4.1/2.7	8.3/7.2	7.5/3.7	7.1/6.3	6116	462	(0.143, 0.191)	59
An-tBCz + 15% of DPaNIF	3.7/2.5	9.2/8.2	9.0/5.0	5.9/5.3	10,500	466	(0.157, 0.275)	69
^{<i>a</i>} Voltage at 1 mA \cdot cm ⁻² and	$1 \text{ cd} \text{m}^{-2} b$	Recorded at m	vinum and 100	$0. cd.m^{-2}$				

"Voltage at 1 mA·cm⁻² and 1 cd·m⁻². "Recorded at maximum and 1000 cd·m⁻



Figure 8. Transient EL signals of OLEDs with the different EMLs: (a) pure **An-tBCz**, (b) 3% of DPaNIF in **An-tBCz**, and (c) 15% of DPaNIF in **An-tBCz** recorded under various driving J of 0.5, 1, 5, and 10 mA cm⁻².

Electroluminescence Properties. An-tBCz, was employed as the emitter and host of the emitting layer (EML) inside blue TTA-based doping-free and TTA-assisted hyperfluorescent OLEDs. The detailed OLED structure and energy levels are listed in Figure 7a. Two hole transport layers 4,4'cyclohexylidenebis[N,N-bis(4-methylphenyl)benzenamine] (TAPC) and tris(4-carbazoyl-9-ylphenyl)amine (TCTA), an EML consisting of An-tBCz and a blue fluorescence emitter 7,7,13,13-tetramethyl-N5,N5,N11,N11-tetraphenyl-7,13-dihydrobenzo-[g]indeno[1,2-b]fluorene-5,11-diamine (DPaNIF), an electron transport layer of 1,3,5-tri(*m*-pyridin-3-ylphenyl)benzene (TmPyPb), an electron injection layer of lithium fluoride (LiF). and a highly reflective aluminum (Al) cathode were used in the fabrication of OLEDs. The thickness of the layer of TAPC was 40 nm; for the layer of TCTA, it was 10 nm; for EML, it was 17.5 nm; for the layer of TmPyPb, it was 40 nm; for the layer of LiF, it was 1 nm, and the thickness of the Al layer was 100 nm. Three devices were fabricated by varying the composition of the EML. In one device, an EML of pristine An-tBCz was used, in the second one, an EML of 3% molecular dispersion of DPaNIF in An-tBCz was used, and in the third one, an EML of 15% molecular dispersion of DPaNIF in An-tBCz was used. The dopant concentration of the EML was optimized well to obtain maximum η_{CE} and η_{EOE} (Table S6 and Figure S12). The EL characteristics of these three blue TTA-based OLEDs are shown in Figure 7b-d. They include current density-brightness-voltage (J-L-V) plots, plots of $\eta_{\rm CE}$, $\eta_{\rm PE}$, and $\eta_{\rm EQE}$ versus L, normalized EL spectra, and color coordinates at 5 V. The parameters are summarized in Table 5. The turn-on voltages at $J = 1 \text{ mA cm}^{-2}$ of these three devices are in the range of 3.7-4.1 V. Their lit-on voltages at L of 1 cd m^{-2} are in the range of 2.5–2.9 V. The device with the EML of pure An-tBCz exhibits relatively high lit-on voltage due to the large energy band gap of emitter An-tBCz, resulting a shorter wavelength EL spectrum with a peak wavelength (λ_{peak}) of 458

nm and a bluer color coordinate of (0.143, 0.120). This deepblue emitting device also shows high maximum current efficiency η_{CE} power efficiency η_{PE} , and η_{EQE} of 4.8 cd A⁻¹, 4.2 lm W⁻¹, and 5.9%, respectively. Taking into account the rather low Φ value of the film of the emitter, this η_{EQE} value is rather high. It is higher than the limit EQE of OLEDs based on prompt fluorescence of 5%,^{18,64} implying the TTA mechanism to be responsible for the exploitation of triplet excitons in the emission. The limit is set according to the equation $\eta_{EQE} = \gamma \times \Phi \times \chi \times \eta_{out}$ as the OLEDs based on prompt fluorescent emitters are characterized by the maximum formation of the exciton used in EL limited by the IQE at 25%.^{18,64} γ is the charge balance factor, and η_{out} is an out-coupling factor.

Notably, the device with the emitting layer of pure An-tBCz shows an excellent efficiency roll-off of ca. 5% in $\eta_{\rm EQE}$ while it is operated at an L of 1000 cd m⁻². With DPaNIF dopant, the devices show enhanced η_{CE} and η_{PE} , as well as a green shift of the EL spectrum (Table S7 and Figures S12 and S13). In addition, the Φ of the **An-tBCz** film doped with 3% DPaNIF is 61.3%. This observation indicates efficient exciton energy transfer from host An-tBCz to the emitter DPaNIF. The HOMO and LUMO energy levels of the host and guest compounds have perfect alignment with each other and with those of the compounds of the transporting layers (Figure 7a), thus improving the charge balance and energy transfer. However, the low concentration (3%) of the emitter in the An-tBCz matrix results in relatively low L and rather high turnon voltage. The turn-on and lit-on voltages (at 1 mA cm⁻² and 1 cd m^{-2} , respectively) are reduced by rising dopant concentration. Hence, the OLED with 15% concentration of DPaNIF in the EML exhibits max. η_{CE} , η_{PE} , and L at 8.5 V of 9.2 cd A^{-1} , 9.0 lm W^{-1} and 10,500 cd m^{-2} , respectively. However, the EL spectrum shows the obvious green color coordinates of (0.157, 0.275), a λ_{peak} of 466 nm, and a wide bandwidth due to the microcavity resonant effect inside the

device. These variations in EL spectra show that the carrier recombination zone shifts with the increasing dopant concentration toward the HTL and broadens inside the EML. At the same time, the $\eta_{\rm EQE}$ decreases due to concentration quenching. The values of full width at high maximum (fwhm) of the OLEDs with lower concentrations are smaller than 60 nm, similar to previously reported devices exhibiting TTA (Table 5).^{26,28}

To verify the TTA mechanism of **An-tBCz**-based OLEDs, time-resolved electroluminescence (TrEL) measurements were performed for the aforementioned three devices by varying pulsed driving *J* (of 0.5, 1, 5, and 10 mA cm⁻², respectively). Figure 8 shows the TrEL signals of the three devices. TTA is manifested from the increase in intensity of long-lived emission at high driving *J*. The increased number of triplets results in the increase of the probability of two triplets meeting together to induce TTA. After the addition of the DPaNIF dopant, the TrEL signals exhibit a longer-lived delayed emission than the TREL of the OLED with the EML of pure **An-tBCz**. This observation indicates that the fluorescent emitter facilitates the TTA process of the **An-tBCz** host, especially in the case of the OLED with the EML containing 15% DPaNIF.

The additional series of OLEDs with the different nonoptimized structures based on the doping-free and guest-host EML were fabricated using An-tBCz, An-MCz, and An-ECz specifically to detect the manifestation of TTA without the aim of achieving satisfactory efficiency or device stability. TTA is a process of the annihilation of two triplet excitons. The delayed fluorescence resulting from TTA has kinetic regimes of low and high annihilation.^{65,66} At the low regime, the correlation between the intensities of delayed fluorescence and excitation is quadratic until the TTA becomes saturated. The dependence becomes linear at the kinetic regime of saturated TTA. This relation corresponds to the slopes of 2 at low J and of 1 at high J of the linear fits of the plot of L vs J in the log-log scale. The slope up to 1.27 was obtained for An-ECz (Figure S14) This value allows us to presume the contribution of TTA in the EL. The devices based on An-MCz did not exhibit slopes higher than 1. Taking into account the detection of long lifetimes and the CT nature of the emission, the possibility of TADF-based EL can be presumed for An-MCz. As the T₁ estimated from theoretical calculations has low energy when compared to that of S_1 , the possible TADF could occur via RISC from the triplet excited state higher than T₁, possibly approaching the HLCT triplet excited state or via a hot-exciton mechanism (Figure S9). TTA and TADF can also be the competitive processes within the single emitting system. OLEDs based on the EML of An-tBCz are characterized by the slopes being close to 1 and higher. The highest obtained slope was 1.79 (Figure S14). The difference in slopes for different devices based on the same emitting species is probably due to the different structures of devices changing the charge balance or the peculiarities of deposition of the layers, stimulating the facilitation of TTA at low J. Anthracene derivatives or anthracene itself can form excimers,^{67–70} meaning that the excimer formation could happen (possibly triplet excimer is responsible for the peak at 1.7 eV in the spectrum shown in Figure S9) in some OLEDs in specific conditions, resulting in the enhancement of delayed fluorescence facilitated through TTA. The L-J correlation (Figure S12) is in the accordance with the TrEL signals discussed for An-tBCz (Figure 8a), confirming the occurrence of TTA for the compound. We additionally measured the

lifetime of the OLED with the EML of the molecular mixture of **An-tBCz** and DPaNIF (Figure S15). The TTA-based devices showed considerably longer operational lifetime than that of the previously reported blue phosphorescent OLED (PhOLED) with FIrpic as the emitter in our lab.⁷¹ The blue PhOLED shows 4 min of LT80 by operating under a luminance of 1000 cd m⁻². The TTA-based OLED developed in this work with the EML of the molecular mixture of **An-tBCz** and DPaNIF showed a considerably longer lifetime with LT80 of 38 min operating under the high luminance of 5000 cd m⁻².

CONCLUSIONS

Three carbazolyl phenyl anthracenyl benzonitriles with different substituents (*tert*-butyl, methoxy, and methoxyethoxy) attached to the C-3 and C-6 positions of the carbazole moiety were obtained by Stille coupling reactions of bromoanthracene with the corresponding stannanes.

The flat anthracene moiety with extended π -conjugation is responsible for the molecular packing in solid layers of the compounds in a way that stimulates formation of intermolecular interactions favorable for the TTA. Compounds containing ethoxy and methoxyethoxy groups show enhanced thermal stability and photoluminescence quantum yields, arising from delayed fluorescence upon photoexcitation. The tert-butyl-containing compound was used for the fabrication of host-free emitting and guest-host emitting layers of the OLEDs. The devices with dopant-free and guest-host emitting layers showed the transient EL signal, which confirmed the delayed emission. Doping-free TTA OLEDs based on TTA showed a maximum external quantum efficiency of 5.9%. The TTA character of the long-living emission was confirmed for the device based on the tert-butyl-containing emitter. The plot of brightness vs current density in the log-log scale was found to be 1.79 in the range of current density of 4-12 mA cm⁻². The utilization of upconverted triplet excitons in EL resulted in the external quantum efficiency reaching 7.1%. This value is higher than the limit of external quantum efficiency of OLEDs based on prompt fluorescent emitters. The hyperfluorescence assisted by TTA upconversion was achieved utilizing a bicomponent host-guest system without the use of a sensitizer. This study highlights the high potential of blueemitting donor-acceptor derivatives of anthracene and carbazole exhibiting triplet fusion in OLEDs.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsaelm.4c00533.

¹H NMR and ¹³C NMR spectra of the compounds; TD-DFT parameters including the triplet state of An-tBCz, An-MCz, and An-ECz in the gas phase; TD-DFT parameters of An-tBCz, An-MCz and An-ECz in toluene solvent; theoretical absorption spectra in gas and solvent phases and experimental spectra in toluene of An-tBCz, An-MCz, and An-ECz; contribution % of different units in FMOs and energy of FMOs with respective E_{gap} of An-tBCz, An-MCz, and An-ECz; DOS plots of the compounds; PL decay curves of the films of AN-tBCz, AN-MCz, and AN-ECz in vacuum at ambient temperature; Jablonski diagram; photo of the films of the compounds deposited by drop casting on the FTO substrates made for IP_{PE} determination under UV photoexcitation; PL spectra with different delays applied measured in Argon at liquid nitrogen temperature; lifetimes of the compounds; TOF signals of An-tBCz, An-MCz, and An-ECz recorded for holes and electrons; thicknesses of An-tBCz, An-MCz, and An-ECz recorded by the profilometer Profilm3D; J-V curves, L-V curves, $\eta_{\rm CE}$ -*J* curves, and $\eta_{\rm PE}$ -*J* curves of **An-tBCz** OLEDs with various DPaNIF dopant concentrations (6, 9, 12, 18, and 20%); EL characteristics of OLEDs with various DPaNIF dopant concentrations (6, 9, 12, 18, and 20%); EL spectra at 5 and 8 V of An-tBCz OLEDs with various DPaNIF dopant concentrations (6, 9, 12, 18, and 20%); plot of dependence of brightness on current density for nonoptimized OLEDs based on EMLs of An-tBCz, An-MCz, and An-ECz; and the lifetime of the OLED with the EML of the molecular mixture of An-tBCz and DPaNIF and of the blue PhOLED (PDF)

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Notes

The authors declare no competing financial interest.

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